## Imaging Spin Reorientation Transitions in Consecutive Atomic Co layers on Ru(0001)

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(Dated: November 10, 2018)

By means of spin-polarized low-energy electron microscopy (SPLEEM), we show that the magnetic easy-axis of one to three atomic-layer thick cobalt films on Ru(0001) changes its orientation twice during deposition: one-monolayer and three-monolayer thick films are magnetized in-plane, while two-monolayer films are magnetized out-of-plane. The Curie temperatures of films thicker than one monolayer are well above room temperature. Fully-relativistic calculations based on the Screened Korringa-Kohn-Rostoker (SKKR) method demonstrate that only for two-monolayer cobalt films the interplay between strain, surface and interface effects leads to perpendicular magnetization.

Keywords: magnetism, magnetic materials, magnetic anisotropy, thin films, spin polarized low energy electron microscopy, Ru, Co

Applications of ferromagnetic lms depend on understanding and controlling the direction of the easy-axis of magnetization In particular magnetization perpendicular to the lm plane 4 holds promise for novel information\_processing technologies 5 Two important features of ultra thin lms underlie this technological achievement: the high Curie temperature of transition metal lms and the ability to control their microstruc. ture To provide deeper understanding we study thin\_-Im magnetism in a system whose components do not intermix Co and Ru Previous work 6 7 has shown that the easy axis of magnetization in Co Ru multilay.ers changes from perpendicular at low Co thickness to in\_plane for lms thicker than 7 ML 8 Because the Co lms did not grow layer.by.layer 9 the lms contained is... lands of varying thickness Under these conditions determining precisely how the magnetization changes as a function of lm thickness is quite problematic

Here we deposit Co lms under conditions of perfect layer by layer growth Then we use in situ spin polarized low-energy electron microscopy (SPLEEM to locally determine the magnetization orientation of one.- two.- and three-monolayer thick Co lms We observe that the easy axis of magnetization changes after the completion of each atomic layer By com. bining structural morphological and microscopic magnetic measurements with fully relativistic ab-initio calculations based on the screened Korringa-Kohn-Rostoker (SKKR 4 method we explain the origin of the magne. tization changes Our results highlight that the magnetic anisotropy of ultra thin lms is not simply explained by strain or interface e ects alone but often by a combination of both  $e_{j}$  ects<sup>5</sup>

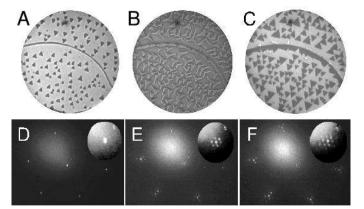


FIG. 1: LEEM images and diffraction patterns of a Co film growing on Ru(0001). (a)-(c): LEEM images show the morphology of the growing film. Field of view is 10  $\mu$ m, electron energy is 5 eV, and growth temperature is 460 K. One single, curved Ru step crosses the images. (a) 1 ML Co islands (dark) on Ru (light gray background). (b) 2 ML islands (light gray) on a complete 1 ML film (dark gray). (c) 3 ML islands (dark gray) on a nearly complete 2 ML film (light gray). (d)-(f) LEED patterns (70 eV) obtained from selected film areas of uniform thickness. Insets show magnified views of the specular beam. (d) 1 ML, (e) 2 ML and (f) 3 ML of Co/Ru(0001).

The lms are grown in two di erent ultra high vacuum low energy electron microscopes (LEEM and SPLEEM by physical vapor deposition from calibrated dosers at rates of ML min Details of the substrate cleaning procedure as well as the experimental system are given elsewhere 6 Perfect layer by layer Co growth occurs up to at least 7 ML when the Ru substrate has a low density of atomic steps (Fig a.c Because substrate steps enable a kinetic pathway to the nucleation of new lm layers three-dimensional growth 8 9 occurs after the rst monolayer if substrate steps are present at even moderate density 7 The lm structure is determined by selected area low energy electron di raction (LEED ie the di raction patterns were acquired with di racted electrons<sup>5</sup> coming from areas of the lm with utiform thickness One-monolayer lms always present  $a \times LEED$  pattern indicating pseudomorphic growth that is the lm has the same in-plane lattice parameter as the substrate (Fig d Since the in-plane lattice parameter of bulk Co is 7 9 % smaller than that of Ru both measured within the hexagonal close packed (hcp basal plane the rst monolayer of Co is under pronounced ten. sile strain Analysis of the intensity versus energy curves of the specular and integer di raction spots establishes that the Co lm continues the hcp stacking 8 of the substrate with a Co.Ru interplanar separation estimated to be contracted 6% relative to the Ru.Ru interplanar spacing For lms thicker than ML satellite spots ap.pear around the bulk di raction beams (Fig e.f i e the thicker lms are no longer pseudomorphic From the di raction patterns we estimate that the in-plane spac. infig of ML and ML Co lms is  $5\pm$  % less than the Ru spacing leaving the lm strained only by % rel. ative to the bulk Co value At intermediate coverages between ML and ML the ML areas are still pseudomorphic as detected by dark - eld imaging 6 while ML islands are relaxed and ML lms grow mainly in

a face\_centered\_cubic structure

To characterize the easy axis of magnetization we em. With this technique the magnetiza. plov SPLEEM tion can be mapped onto three orthogonal directions 9: the absence of contrast in the images (gray indicates no magnetization component along the selected direction; bright and dark areas indicate a component of the magnetization along or opposed to the illuminating beam polarization respectively In Fig we show LEEM and SPLEEM images of a lm that consists of a complete monolayer of Co plus some second layer islands (Fig a both in the middle of the substrate terraces and at the bottom of the ruthenium substrate steps The SPLEEM images show the spatially resolved component of the magnetization in three orthogonal directions: two in plane (Fig b.c and one out of plane (Fig d In one monolayer areas the magnetization is oriented in the plane of the lm while for two layer islands the mag.netization is out of plane For a complete ML lm with additional ML islands (Fig the magnetiza. tion of the ML areas is out of plane In contrast ML thick islands and thicker lms (not shown are magne.tized in plane To summarize two magnetization easy\_axis reorientation transitions are found in three consecutive atomic layers: at the crossover between and ML ML This behavior has also been and between and con rmed in lms devoid of islands We do not nd inter-

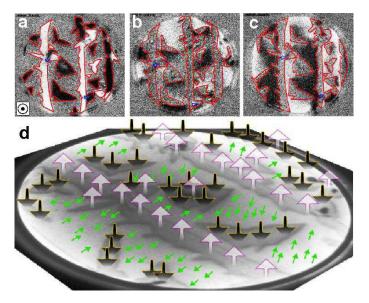


FIG. 2: (color) Images of topography and magnetization of one region of a 1.5 ML Co/Ru(0001) film. Images were taken at 110 K. Field of view is 2.8  $\mu$ m and electron energy is 7 eV. (a)-(c) SPLEEM images with electron-polarization oriented: (a) out-of-plane; (b) in-plane and 13° off a compact-direction; (c) in-plane and 103° off a compact-direction. 2 ML islands are framed in red (two small 3 ML islands are framed in blue). (d) LEEM image of the surface with the deduced magnetization direction indicated by arrows (black and white arrows mean out-of-plane magnetization, green arrows mean in-plane magnetization). Dark gray indicates 2 ML islands, light gray 1 ML film.

mediate easy\_axis orientations (i e in between in\_plane and out\_of\_plane such as observed for Co lms on other substrates The Curie temperature of the lms changes dramatically from the second The rst layer has a Curie temperature close to 7 K as detected by the loss of magnetic contrast in the ML areas The Curie temperature of the ML islands which are magnetized out\_of\_plane is well above room temper\_ature about 47 K Thicker lms exhibit Curie temper. atures above 47 K Iron lms on W( also present a double spin reorientation transition but with a Curie temperature well below room temperature for out\_of plane magnetization 4 In this particular system strain did not drive the reorientation transitions 4 5

The anisotropy energy that governs the orientation of the easy axis of magnetization is the result of a delicate balance between digerent contributions. In thin lms the dominating term is often the dipolar or shape anisotropy This contribution which results from the long-range magnetic dipole dipole interactions favors an in-plane orientation of the magnetization. However, other contributions such as the bulk interface and surface magnetocrystalline anisotropy energies as well as magneto-elastic terms 5 6 can compete with the dipolar anisotropy energy and can favor out of plane magnetization. To un-

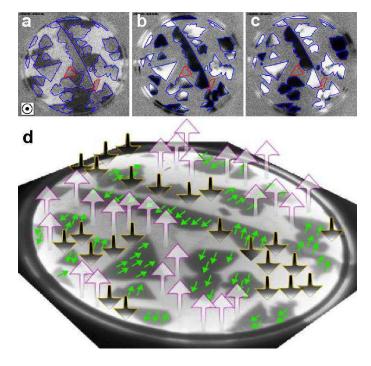


FIG. 3: (color) Images of topography and magnetization of one region of a 2.5 ML Co/Ru(0001) film. Images were taken at room temperature. Field of view is 2.8  $\mu$ m and electron energy is 7 eV. (a)-(c) SPLEEM images with electronpolarization oriented: (a) out-of-plane; (b) in-plane and 13° off a compact-direction; (c) in-plane and 103° off a compactdirection. 3 ML islands are framed in blue. Two vacancyislands in the 2 ML area, where Co is 1 ML thick, are framed in red. (d) LEEM image of the surface with the deduced magnetization direction indicated by arrows (black and white arrows mean out-of-plane magnetization, green arrows mean in-plane magnetization). Dark gray indicates 3 ML islands, light gray 2 ML film.

derstand the e ects that give rise to the observed changes in the orientation of the Co magnetization we perform ab initio calculations in terms of the SKKR method 4 Changing the lattice parameters in the calculations allows us to determine how strain in uences the magnetic anisotropy The magnetic anisotropy energy (MAE is calculated as the difference of the total energy for inplane and out of plane magnetization A positive MAE corresponds to out of plane magnetization By employing the force theorem 7 the MAE is de ned as the sum of a band energy  $\Delta E_b$  and a magnetic dipoledipole energy term  $\Delta E_{dd}$  The band energy term can be further resolved into contributions with respect to atomic layers that enable us to de ne surface and interface anisotropies

First we calculate the anisotropy of the pseudomorphic one-monolayer Co lms taking into account contractions of the Co-Ru interlayer distance (d As summarized in Fig 4a the value of  $\Delta E_b$  increases as the interplanar spacing decreases; however due to the negative  $\Delta E_{dd}$  the preferred orientation of the magnetization remains always in plane Interestingly the change in MAE is not proportional to the strain and therefore simple magnetoelastic arguments do not apply Furthermore we also tested the e ect of contracting the in plane lattice parameter of substrate and lm In that case the MAE does not change signi cantly (result not shown in the gure We conclude that the magnetization of the monolayer remains in plane regardless of strain

For two monolayer and thicker lms the in-plane separation of the Co atoms is contracted by  $\sim 5\%$  with respect to the Ru structure leading to a x coincidence lattice. We model the in-plane relaxation by contracting the supporting Ru substrate together with the Co lm Under this assumption taking the same contraction for the Co.Co and Co.Ru interlayer spacing d from

to 7% relative to the substrate interlayer distance leads to a positive value of  $\Delta E_b$  (Fig 4b that however does not compensate the negative  $\Delta E_{dd}$  For the bilayer the observed positive sign of the MAE occurs when digerent values for the Co.Co and Co.Ru interlayer distances are considered In order to estimate the preferred relaxation of the interlayer distances we assume that atoms try to maintain the nearest-neighbors (NN distances of their bulk materials with Co.Ru distances being an average of the preferred Co.Co and Ru.Ru interlayer distances This leads to contractions of 7% for the Co-Co interlayer distances and a nearly unrelaxed Co.Ru spacing As shown in Fig 4b (leftmost data points such a lattice distortion considerably increases  $\Delta E_b$  resulting in a total positive MAE A positive MAE is also obtained for an ideal Ru lattice with Co interlayer distances contracted by more than 4% (not shown In ML thick lms non-uniform contractions of the Co layers lead also to an enhancement of the positive  $\Delta E_b$  (Fig 4c Nevertheless the decrease in the  $\Delta E_{dd}$  term associated with thicker lms drives the magnetization in plane A summary of our calculations of the MAE for the Co lms of digerent thickness each at the most likely geometry is shown in Fig 4d As a function of thickness the MAE changes sign twice as observed experimentally

Our calculations show that the double spinreorientation transition is the result of a complicated interplay of structural and interface surface electronic e ects All contributions to  $\Delta E_b$  are strongly in uenced by structural modi cations For ML thick lms with the same Co Co and Co Ru interlayer separation the dominant term is  $\Delta E_b$  related to the interface Co However when Co Co and Co Ru separations are allowed to be di event the contribution of the surface Co layer is remarkably enhanced resulting in a positive value of the MAE (out of plane magnetization

In conclusion we deposited lms of Co onto Ru( in the thickness range of up to atomic monolayers and nd that the Curie temperature is well above room temperature provided the thickness is more than a single

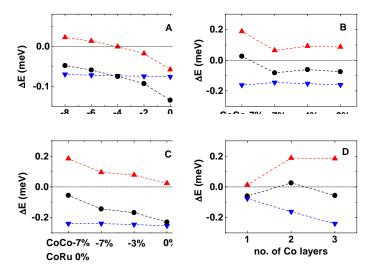


FIG. 4: (color) Calculated magnetic anisotropy energies of the different Co films on Ru. (a)-(c) Dependence of the calculated MAE on the interlayer distance referred to the substrate interlayer spacing. MAE (black circle) and its components,  $\Delta E_b$  (red up-triangle) and  $\Delta E_{dd}$  (blue down-triangle) for: (a) a pseudomorphic 1 ML Co/Ru(0001) film under different contractions of the Co-Ru interlayer distance; in-plane strained (b) 2 ML Co/Ru(0001) and (c) 3 ML Co/Ru(0001) films with either the same or different (data points labelled by CoCo -7% and CoRu 0%) Co-Co and Co-Ru interlayer separations. (d) MAE and its components in the most realistic geometry for the 1, 2 and 3 ML Co films on Ru(0001), displaying the double reorientation transition.

atomic monolayer We observe two sharp reorientation transitions of the magnetization: ML as well as ML or thicker Co lms have an in-plane easy axis while only

ML thick lms are magnetized in the out of plane direction The rst transition is associated with a structural transformation from laterally strained pseudomorphic ML thick lms to relaxed ML thick lms Our rst principles calculations show that the in-plane easyaxis of one - and three monolayer lms is stable with respect to variations of the strain conditions Only for two monolayer lms the combination of strain with additional interface and surface e ects drives the magnetic easy axis into the out of plane direction

This research was partly supported by the U S Department of Energy under contract DE-AC .- $5\mathrm{CH}$ by the Spanish Ministry of Science and Technology under Projects No MAT - 86 7 --С .-MAT -4 78 and 4.HU and by the Comunidad Autónoma de Madrid under Project 4 Additional support by the Hun.-GR MAT 55garian Scienti c Research Fund (OTKA T 7856 and T 46 67 and the Austrian Ministry of Labor and Economy (bw:aw 98 66 is acknowledged

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